Zibo Seno Electronic Engineering Co., Ltd.

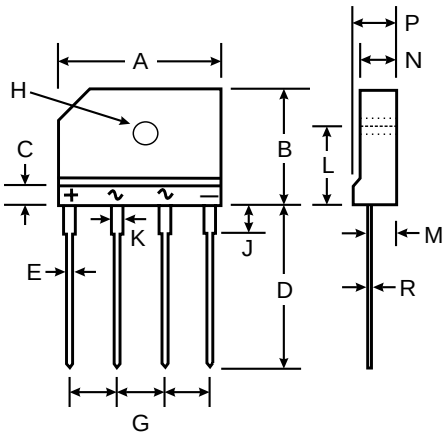
淄博圣诺

KBJ6A - KBJ6M

6.0A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- High Case Dielectric Strength of 1500V_{RMS}
- Low Reverse Leakage Current
- Surge Overload Rating to 170A Peak
- Ideal for Printed Circuit Board Applications
- Plastic Material - UL Flammability Classification 94V-0
- **Lead Free:For RoHS / Lead Free Version**



KBJ4		
Dim	**Min**	**Max**
A	24.80	25.20
B	14.70	15.30
C	4.00 Nominal	
D	17.20	17.80
E	0.90	1.10
G	7.30	7.70
H	3.10 ∅	3.40 ∅
J	3.30	3.70
K	1.50	1.90
L	9.30	9.70
M	2.50	2.90
N	3.40	3.80
P	4.40	4.80
R	0.60	0.80
All Dimensions in mm		

Mechanical Data

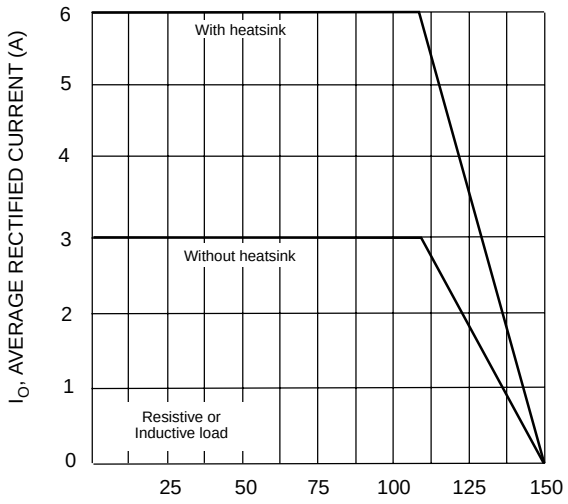
- Case: Molded Plastic
- Terminals: Plated Leads, Solderable per MIL-STD-202, Method 208
- Polarity: Molded on Body
- Mounting: Through Hole for #6 Screw
- Mounting Torque: 5.0 in-lbs Maximum
- Weight: 6.6 grams (approx)
- Marking: Type Number

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

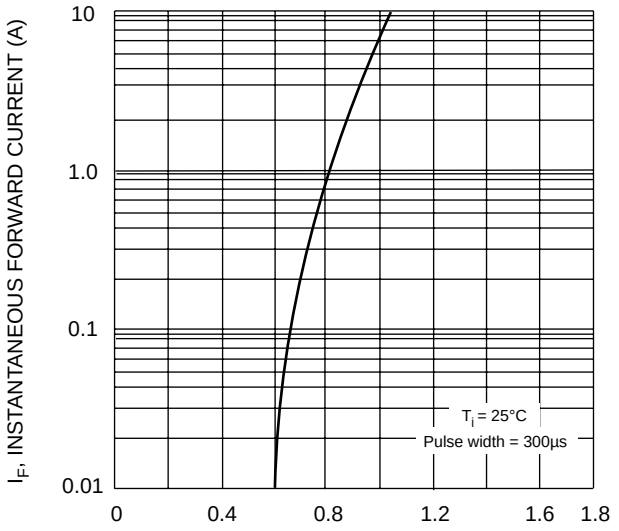
Characteristic	Symbol	KBJ 6A	KBJ 6B	KBJ 6D	KBJ 6G	KBJ 6J	KBJ 6K	KBJ 6M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Forward Rectified Output Current @ T_C = 110°C	I_O	6.0							A
Non-Repetitive Peak Forward Surge Current, 8.3 ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	170							A
Forward Voltage per element @ I_F = 3.0A	V_{FM}	1.0							V
Peak Reverse Current @ T_C = 25°C at Rated DC Blocking Voltage @ T_C= 125°C	I_R	5.0 500							μA
I^2t Rating for Fusing (t < 8.3ms) (Note 1)	I^2t	120							A^2s
Typical Junction Capacitance per Element (Note 2)	C_j	55							pF
Typical Thermal Resistance Junction to Case (Note 3)	$R_{\theta JC}$	1.8							°C/W
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150							°C

Notes: 1. Non-repetitive, for t > 1ms and < 8.3 ms.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
3. Thermal resistance from junction to case per element. Unit mounted on 75 x 75 x 1.6mm aluminum plate heat sink.



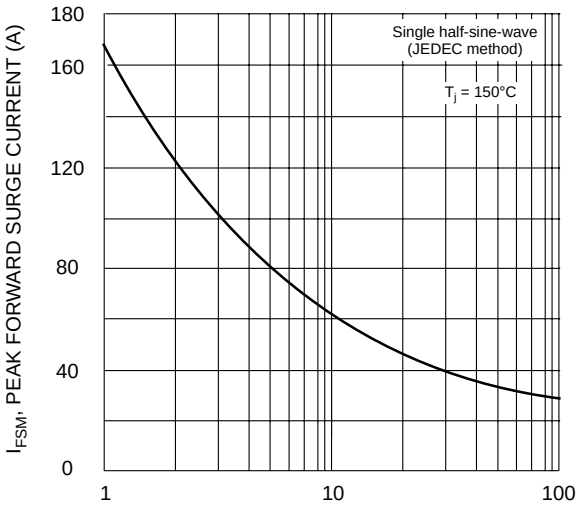
T_C, CASE TEMPERATURE (°C)

Fig. 1 Forward Current Derating Curve



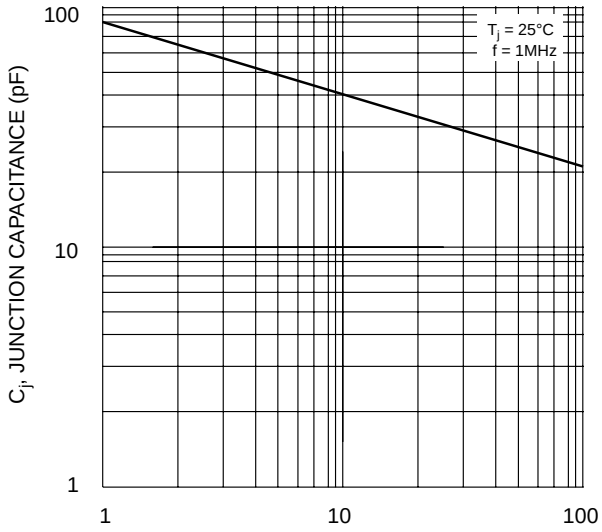
V_F, INSTANTANEOUS FORWARD VOLTAGE (V)

Fig. 2 Typical Forward Characteristics (per element)



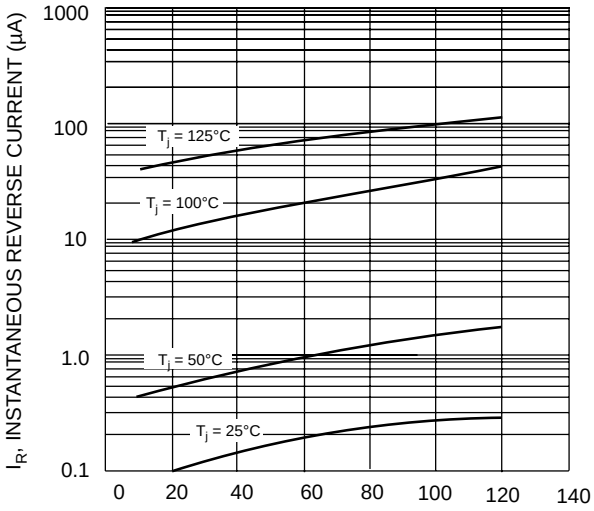
NUMBER OF CYCLES AT 60 Hz

Fig. 3 Maximum Non-Repetitive Surge Current



V_R, REVERSE VOLTAGE (V)

Fig. 4 Typical Junction Capacitance



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

Fig. 5 Typical Reverse Characteristics